NSN 5961-01-318-8808

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-318-8808 **End Application:** Mesp **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon **Special Features:** Selected from p/n jantx1n3022b; jantxv1n3022b; fscm 81349; hardness critical item **Nuclear Hardness Critical Feature:** Hardened **Test Data Document:** 63812-8856222 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

No

Fiig:

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